Laser-enhanced Atomic Mobility and Nanoparticles Formation in Porous Glass

Luca Marmugi

CNISM and Department of Physical Sciences, Earth and Environment - University of Siena via Roma 56, 53100 Siena

INO-CNR, UOS Pisa, via G. Moruzzi 1, 56124 Pisa

luca.marmugi@ino.it





INO-CNR Istituto Nazionale di Ottica

INO - UOS "A. Gozzini" Pisa, March 7th 2014



Introduction

Adsorption, desorption and surface interaction.

Adsorption and desorption influence atom/substrate interaction.

 \blacksquare Direct influence on atomic mobility: dynamics and evolution at the nanoscale.



Introduction

Adsorption, desorption and surface interaction.

Adsorption and desorption influence atom/substrate interaction.

Direct influence on atomic mobility: dynamics and evolution at the nanoscale.

Adsorption and desorption can be controlled by light.



[A. Gozzini et al., Il Nuovo Cimento D 15, 5, 709, 1993]

venerdì 7 marzo 2014





RT vapor density stabilization and modulation:
 all-optical atomic dispenser.



[A. Bogi et al., Opt. Lett. **34**, 17, 2643, 2009]



INO-CNR ISTITUTO NAZIONALE DI OTTICA

RT vapor density stabilization and modulation:
 all-optical atomic dispenser.



[A. Bogi et al., Opt. Lett. **34**, 17, 2643, 2009]



UNIVERSITĂ DI SIENA 1240

INO-CNR Istituto Nazionale di Ottica

➡ RT EIT in optically stabilized vapors: costant, improved C and 33 kHz FWHM.



L. Marmugi et al., J. Opt. Soc. Am. B **29**, 10, 2729, 2012



UNIVERSITA DI SIENA

> INO-CNR Istituto Nazionale di Ottica

RT EIT in optically stabilized vapors: costant, improved C and 33 kHz FWHM.



L. Marmugi et al., J. Opt. Soc. Am. B **29**, 10, 2729, 2012

Localized Surface Plasmons.



- Interaction between photon EF and CB e⁻ metal NP.
- Non propagating \Rightarrow Localization.
- $k=0 \Rightarrow PM$ with incoming radiation.
- Quasi-static and dipole approximation => 2a < 20 nm

Localized Surface Plasmons.



Localized Surface Plasmons: Gans approach.

$$\alpha_j(\omega) = \varepsilon_0 \frac{\varepsilon(\omega) - \varepsilon_m}{\varepsilon_m + [\varepsilon(\omega) - \varepsilon_m]L_j} V$$

$$\sigma_{ext}^{Gans} = V \frac{\omega}{3c} \varepsilon_m^{3/2} \sum_{j=a,b,c} \frac{\varepsilon_2(\omega)/L_j^2}{\varepsilon_2^2(\omega) + \left[\varepsilon_1(\omega) + \varepsilon_m \frac{1-L_j}{L_j}\right]^2}$$

UNIVERSITÀ DI SIENA

Localized Surface Plasmons: Gans approach.

$$\alpha_j(\omega) = \varepsilon_0 \frac{\varepsilon(\omega) - \varepsilon_m}{\varepsilon_m + [\varepsilon(\omega) - \varepsilon_m]L_j} V$$

2



UNIVERSITÀ DI SIENA



Porous glass

PG: a small flat on a fingertip.





- SiO₂ 96%
 B₂O₃ 3%
- Traces: Na₂O, Al₂O₃, ZrO₂

Spinodal decomposition:
domains ~t^{1/2}
average radius ~t



Porous glass

PG: a small flat on a fingertip.



- SiO₂ 96%
 B₂O₃ 3%
- Traces: Na₂O, Al₂O₃, ZrO₂

Spinodal decomposition:
domains ~t^{1/2}
average radius ~t



Porous glass

PG: a small flat on a fingertip.



- Average pore diameter: 20 nm.
- Free volume: 0.55.
- Internal surface: 31 m².



Light-induced atomic desorption in PG [A. Burchianti *et al.*, Europhys. Lett. **67**, 6, 983, 2004].





➡ Light-induced atomic desorption in PG [A. Burchianti et al., Europhys. Lett. 67, 6, 983, 2004].

Adsorption and desorption at the pores surface : reversible formation of metal NPs [A. Burchianti *et al.*, Phys. Rev. Lett. **97**, 157404, 2006].



→ Light-induced atomic desorption in PG [A. Burchianti et al., Europhys. Lett. 67, 6, 983, 2004].

- Adsorption and desorption at the pores surface : reversible formation of metal NPs [A. Burchianti *et al.*, Phys. Rev. Lett. **97**, 157404, 2006].
- ➡ Memory effect due to light-induced phase-transformations [A. Burchianti et al., Opt. Expr. 16, 2, 1377, 2008].





→ Light-induced atomic desorption in PG [A. Burchianti et al., Europhys. Lett. 67, 6, 983, 2004].

Adsorption and desorption at the pores surface : reversible formation of metal NPs [A. Burchianti *et al.*, Phys. Rev. Lett. **97**, 157404, 2006].

➡ Memory effect due to light-induced phase-transformations [A. Burchianti et al., Opt. Expr. 16, 2, 1377, 2008].

Green-blue Light	
Pore surface	pore surface
NIR Light	





➡ Light-induced atomic desorption in PG [A. Burchianti et al., Europhys. Lett. 67, 6, 983, 2004].

Adsorption and desorption at the pores surface : reversible formation of metal NPs [A. Burchianti *et al.*, Phys. Rev. Lett. **97**, 157404, 2006].

➡ Memory effect due to light-induced phase-transformations [A. Burchianti et al., Opt. Expr. 16, 2, 1377, 2008].





Identification of spheroidal NPs [A. Burchianti et al., Eur. Phys. J. D. 49, 201, 2008].

Experimental apparatus

"Static" characterization: absorbance analysis.



Experimental apparatus

"Dynamic" characterization: time evolution.



- K vapor density: ECDL @ 770.1 nm (K D1 line), ~2.5 GHz sweep, 47 Hz
- Desorbing lights: LD @ 660 nm, DPSSL @ 532 nm, LD @ 405 nm
- TPBs: LD @ 730 nm, 780 nm, 830 nm, 850 nm, 1460 nm
- DAQ: I/O multi-channel, background subtraction+resonance following, illumination timing

Two simultaneous processes.



 $\hbar\omega_{exp} = 1.66 \pm 0.02 \text{ eV}$

UNIVERSITĂ DI SIENA 1240

Two simultaneous processes.



 $\hbar\omega_{exp} = 1.66 \pm 0.02 \text{ eV}$

UNIVERSITĂ DI SIENA 1240

Two simultaneous processes.



Two simultaneous processes.



UNIVERSITĂ DI SIENA 1240

Two simultaneous processes.



$$\varepsilon_{eff} = 2.04$$

$$\hbar\omega_p = 3.72 \text{ eV}$$

$$\hbar\omega_{LSP} = \frac{\hbar\omega_p}{\sqrt{1 + 2\varepsilon_{eff}}} = 1.65 \text{ eV}$$



60 mW/cm² at 635 nm, 120 s: low desorption regime.





350 mW/cm² at 532 nm: desorption regime.



Light as a NPs maker.



5 mW/cm² at 405 nm: efficient desorption regime.



Light as a NPs maker.

UNIVERSITÀ DI SIENA 1240

Absorbance spectra

Near-infrared peak: light-induced self-assembly.

350 mW/cm² @ 532 nm

5 mW/cm² @ 405 nm





UNIVERSITÀ DI SIENA 1240

Absorbance spectra

Near-infrared peak: light-induced self-assembly.

350 mW/cm² @ 532 nm

5 mW/cm² @ 405 nm







2 nm prolates, AR=0.75

UNIVERSITÀ DI SIENA 1240

Absorbance spectra

Near-infrared peak: light-induced self-assembly.

350 mW/cm² @ 532 nm

5 mW/cm² @ 405 nm







2 nm oblates, AR=1.25



2 nm prolates, AR=0.75



Near-infrared peak: relaxation in the dark.

After 350 mW/cm² @ 532 nm



After 5 mW/cm² @ 405 nm





2 nm oblates, AR=1.25



I. Adsorption in the dark.



UNIVERSITÀ DI SIENA 1240

I. Adsorption in the dark.



II. Light-induced desorption: enhanced atomic mobility.



UNIVERSITA DI SIENA

I. Adsorption in the dark.



II. Light-induced desorption: enhanced atomic mobility.



III. NPs self-assembly.



venerdì 7 marzo 2014

DI SIEN/



350 mW/cm² @ 532 nm



5 mW/cm² @ 405 nm





2 nm oblates, AR=1.25



2 nm prolates, AR=0.75



350 mW/cm² @ 532 nm



5 mW/cm² @ 405 nm





Light as a NPs shaper.



2 nm oblates, AR=1.25

2 nm prolates, AR=0.75



After 350 mW/cm² @ 532 nm





2 nm oblates, AR=1.25

After 5 mW/cm² @ 405 nm





2 nm prolates, AR=0.75

venerdì 7 marzo 2014



After 350 mW/cm² @ 532 nm



After 5 mW/cm² @ 405 nm







2 nm prolates, AR=0.75

2 nm oblates, AR=1.25

System time evolution

385 mW/cm² at 660 nm: low mobility regime.



System time evolution

40 mW/cm² at 532 nm: light-enhanced mobility regime.



System time evolution

5 mW/cm² at 405 nm: light-enhanced high mobility regime.

















Light-enhanced atomic mobility, NP, atomic motion.



venerdì 7 marzo 2014











Thank you for your attention and for these wonderful years together!



venerdì 7 marzo 2014